

Optoelectronic Devices Based On Thin Single-Crystalline Semiconductor Films And Non-**Epitaxial Optical Cavities**

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The Invention

Optoelectronic devices that use very thin single-crystalline inorganic semiconductor films as phonon-absorbing layers in combination with non-lattice optical cavities are provided.

Additional Information

For More Information About the Inventors

- <u>Zhenqiang Ma</u>
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Publications

• Read a news story about this technology.

Tech Fields

- Analytical Instrumentation, Methods & Materials : Optics
- Semiconductors & Integrated Circuits : Components & materials

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